

AMP²: a fully automated program for ab initio calculations of crystalline materials

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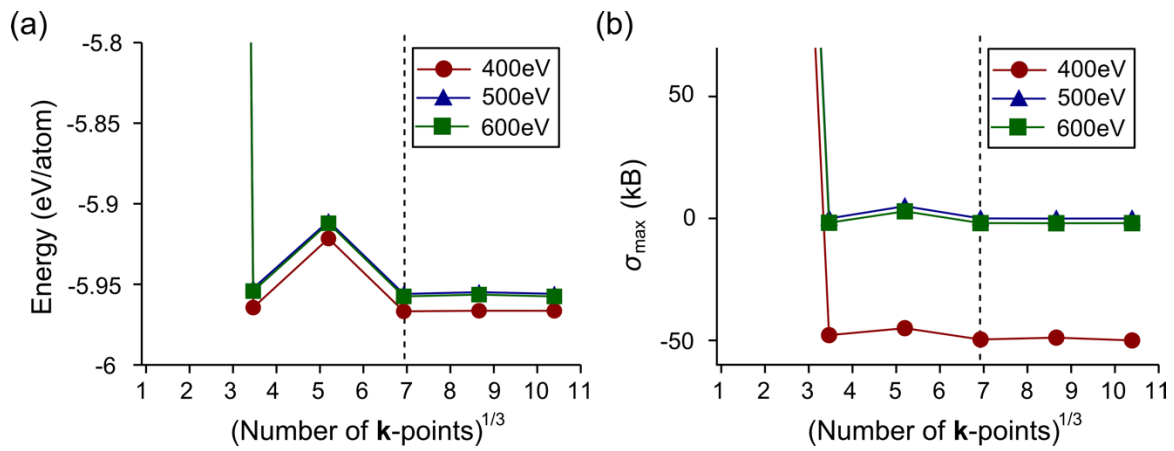


Figure S1 (a) Energy and (b) σ_{\max} convergence test of \mathbf{k} -points for MgO. The vertical dashed lines indicate the converged \mathbf{k} -points. The convergence of the energy (a) and pressure (b) for MgO with respect to the \mathbf{k} -point grid, evaluated at the cutoff energy of 400, 500, and 600 eV. (400 eV is the default value of VASP while AMP² gives 500 eV for the converged E_{cut} .) It is seen that the convergence behavior of \mathbf{k} -point is similar among different cutoff energies except for rigid shifts, meaning that the converged \mathbf{k} -point grid can be safely determined at the default cutoff energy (as is currently done in AMP²).

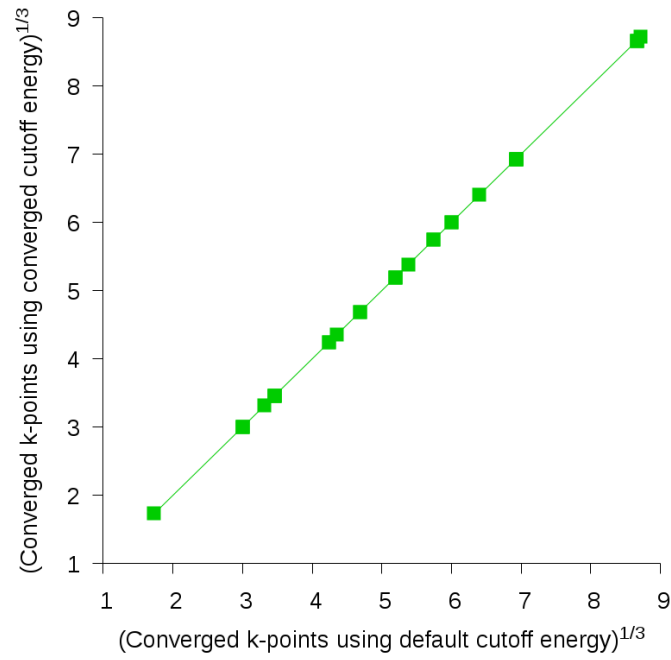


Figure S2 Converged k-point grids for default and converged cutoff energies for 30 randomly chosen materials. (BaSn, BrCs, CuCl, CaH₂, CaNi₃, H₂Sr, La₃Sn₇, Li₁₃Sn₅, Mn₃Sn, P₃N₅, NaTaO₃, SiO₂, ZnS, Tl₂S₃, Ga₁₀La₂Ni, GeLaRu, GePtSe, GeRhSc, IrI₃Te₆, InTaS₂, In₂PbS₄, Ir₂Y₂O₇, KLiSe, KNbO₃, K₂SnTe₃, NaNbN₂, Na₆Sn₂Se₇, Nb₄SiTe₄, NiPSe₃, and PdSc₆Te₂) They show perfect agreements. Therefore, we conclude that the converged k-point grid is insensitive to the cutoff energy and the convergence test can be carried out independently with respect to the k point and cutoff energy.

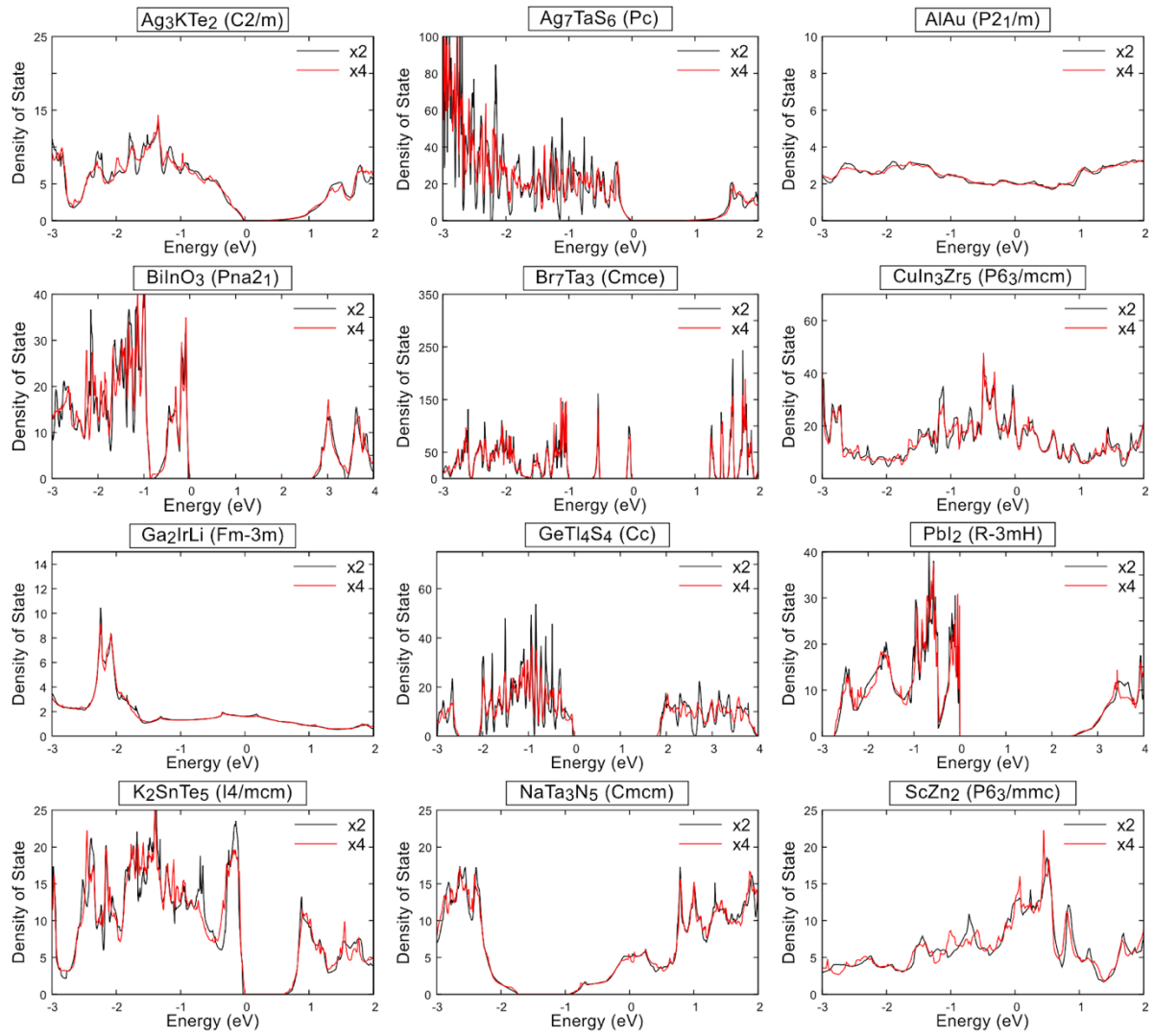


Figure S3 Density of states of Ag_3KTe_2 , Ag_7TaS_6 , AlAu , BiInO_3 , Br_7Ta_3 , CuIn_3Zr_5 , Ga_2IrLi , GeTe_4S_4 , PbI_2 , K_2SnTe_5 , NaTa_3N_5 , and ScZn_2 with the different k-point grids. As shown in the figure, k-point doubling is sufficient for DOS figures.

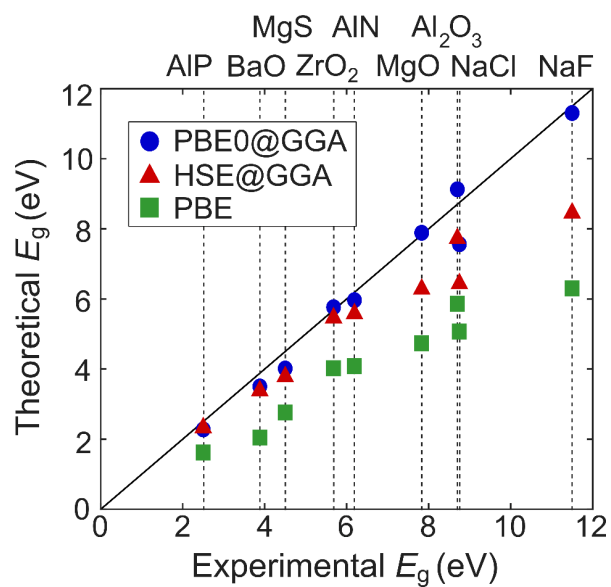


Figure S4 Comparison of theoretical and experimental band gap.[1–6] The solid line indicates perfect agreement with experiment.

Tests for gap-corrected band structure

For materials whose conduction band and valence bands are separated or touch each other (ex. Ag_2O , InAs , Ge , and InSb) within GGA, AMP² consistently produced gap-corrected band structures as guaranteed by the proposed algorithm. When conduction and valence bands overlap each other, AMP² worked well for PdO , PtO , Pb_2PtO_4 , and Sn_3O_4 but failed to separate them in Cd_3As_2 and CaPd_3O_4 . While it is difficult to specify and quantify a feature in band structures that splits success versus failure, we find that GGA and HSE band structures are significantly different in the two materials. For example, the figure below compares GGA and HSE band structures of CaPd_3O_4 , respectively. Based on the HSE result, one can visually identify in the GGA band structure the conduction and valence bands that should move up and down upon gap correction, as indicated by red and blue lines, respectively. One can see that some parts of the lines are broken as indicated by the dashed lines, which is due to the orbital hybridization between conduction and valence bands. This is in contrast with Fig. 5 in the manuscript in which the hybridization is weak. Therefore, the proposed scheme would fail because orbital characters are highly mixed in the broken regions.

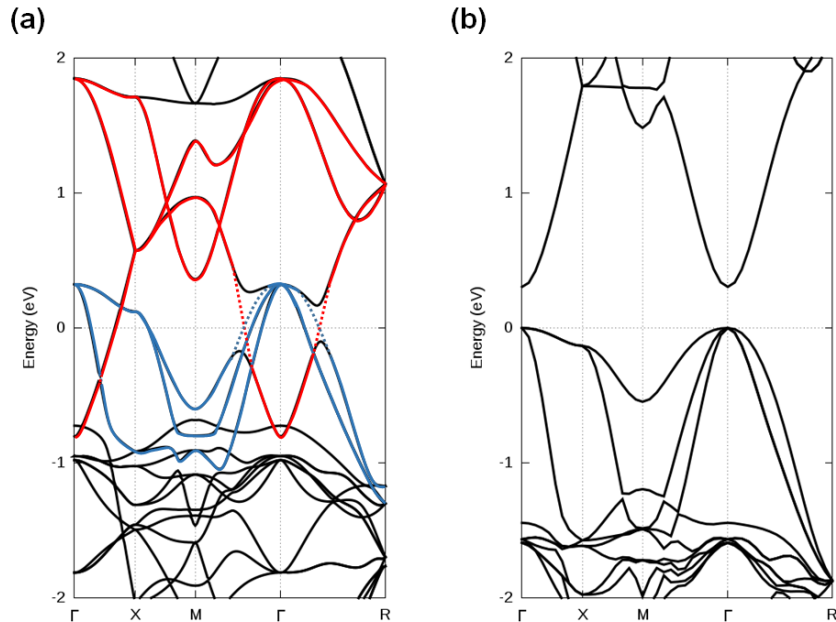


Figure S5 Band structure of CaPd_3O_4 using (a) GGA, (b) HSE functionals, respectively.

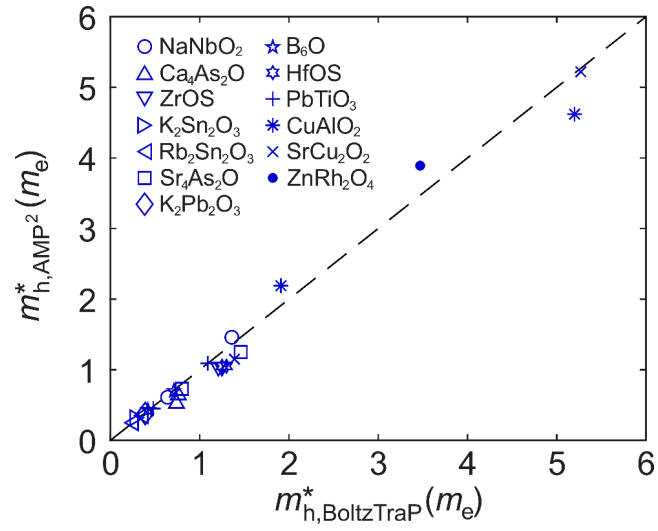


Figure S6 Comparison of principle components of hole effective mass tensor between AMP² and Boltztrap.[7] The solid line indicates perfect agreement.

Table S1. The list and success/failure of 100 materials.

Chemical formula
(ICSD number)

Materials with successful termination (86)					
AgAsSe ₂ (20087)	CoGeNb (623540)	K ₂ CuF ₄ (15372)	LuN (236553)	RbInTe ₂ (75346)	VPO ₅ (108983)
AgBr (52246)	Cr(Te ₂ Rh) ₂ (626579)	K ₂ SnBr ₆ (35557)	LuTlS ₂ (642581)	RbSb (280591)	YZn ₃ (106227)
AlCs ₆ Sb ₃ (300128)	CS ₂ (15672)	KC ₈ (70020)	Mg ₃ Au (58541)	Sc(P ₂ Rh ₃) ₂ (182778)	Y ₄ GaCo ₄ (20953)
AlFe ₂ Ni (57808)	Cs ₂ PtI ₆ (201309)	KCd ₄ As ₃ (262032)	MgB ₂ (108064)	ScInCu ₂ (103009)	Y ₅ S ₇ (43620)
AsPd ₅ (44042)	Cu ₃ Sb (44479)	La(Ge ₃ Pt) ₄ (174552)	MnPd ₂ (247774)	SiC (24630)	YIr ₂ (104601)
B ₂ Mo ₂ Ir (23786)	FeSi ₂ (24360)	La(Sb ₃ Ru) ₄ (641783)	Na ₂ BiAu (261790)	SrF ₂ (262349)	YSnPd ₂ (105699)
BaNiO ₂ (15760)	Ga ₂ Se ₃ (35028)	LaCdPd (656599)	Na ₂ HgPb (261791)	SrIr ₂ (104564)	ZnO (190802)
BeBr ₂ (92584)	Ga ₃ Fe (631756)	LaGa ₂ (103766)	NaMoF ₆ (27484)	SrMnBi ₂ (100025)	Zr ₅ Sb ₃ Ru (650598)
BiI (1559)	Ge ₂ Mo (16822)	Li ₂ Si (24146)	NaN ₃ (644523)	Ta ₂ N (185289)	ZrAg (58390)
Ca(InP) ₂ (260562)	Hf ₂ SN ₂ (250915)	Li ₆ Br ₃ N (16798)	Nb ₇ (BC) ₄ (411624)	Ta ₅ Ge ₃ (195542)	ZrNi ₃ (105482)
Ca(MnAs) ₂ (41792)	Hf ₃ B ₂ Ir ₅ (44316)	LiAg ₂ Sn (151446)	PbI ₂ (108906)	TaRu (650690)	ZrSiRu (16306)
Ca ₂ Ag ₇ (55510)	HfFeCl ₆ (39817)	LiGa ₂ Pt (106717)	PdCl ₂ (421220)	TaSiRh (90435)	
Ca ₃ Al ₇ Ag ₂ (104173)	Hg ₂ Rh (106786)	Lu ₂ ReC ₂ (618232)	PtO ₂ (77654)	TeIr (44870)	
CaSb ₂ (862)	HgCl (157979)	Lu ₃ Al ₂ (57959)	Rb ₂ HgF ₄ (72352)	Ti ₄ P ₃ (648219)	
CdTe (246692)	ICI (23886)	LuIn ₃ (51969)	Rb ₇ TiCl ₆ (26689)	Tl ₂ ZnI ₄ (37099)	

Material with any kinds of errors (14)			
Material	Stage in error	Reason	Category
BaCoS ₂ (82639)	Magnetic ordering	Not converge	Termination
Cl ₃ NW (165376)	Effective mass	Memory	Crash
Cr(Mo ₃ Se ₄) ₂ (626324)	Kptest_w/o U	Not converge	Termination
Cr ₂ GaC (419116)	Kptest_w/o U	Not converge	Termination
CsTiBr ₃ (400053)	Magnetic ordering	EDDDAV	Crash
Fe ₄ O ₅ (185514)	Magnetic ordering	Not converge	Termination
Mn ₂ Au (58548)	Magnetic ordering	Not converge	Termination
Mn ₃ As (76409)	Magnetic ordering	Not converge	Termination
Ni ₂ PdSe ₂ (419760)	Magnetic ordering	Not converge	Termination
NiF ₃ (87943)	Effective mass	Memory	Crash
Sr ₃ GeO (413385)	HSE	Memory	Crash
V ₅ Ge ₃ (44504)	Magnetic ordering	Not converge	Termination
VS ₂ (68713)	Kptest	Not converge	Termination
Y(Fe ₂ Si) ₂ (186048)	Magnetic ordering	Not converge	Termination

When we briefly checked for the magnetic ordering from Ising models, every computational result was reasonable except for FeHfCl₆ and K₂CuF₄ whose spin ordering are mistaken. FeHfCl₆ was reported as antiferromagnetic materials but it has ferromagnetic spin-ordering in AMP².^[8] This is because the antiferromagnetic coupling between Fe ions exceeds the present cutoff of 5 Å. When we increased the cutoff distance, AMP² correctly predicts the antiferromagnetic spin ordering. However, energy difference is almost negligible (only 0.4 meV/Fe atom). On the other hand, K₂CuF₄ is a well-known two-dimensional ferromagnetic material but AMP² predicts an antiferromagnetic ordering.^[9,10] It is known that the ferromagnetic order is more stable only if Jahn-Teller distortion is taken into account but the structure from ICSD is symmetric without Jahn-Teller distortions. When the symmetry is broken, we find that AMP² produces correct results.

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